

CD4028B Types

BCD-to-Decimal Decoder

High-Voltage Types (20-Volt Rating)

■ CD4028B types are BCD-to-decimal or binary-to-octal decoders consisting of buffering on all 4 inputs, decoding logic gates, and 10 output buffers. A BCD code applied to the four inputs, A through D, results in a high level at the selected one of 10 decimal decoded outputs. Similarly, a 3-bit binary code applied to inputs A through C is decoded in octal code at output 0 to 7 if D = "0". High drive capability is provided at all outputs to enhance dc and dynamic performance in high fan-out applications.

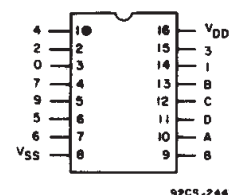
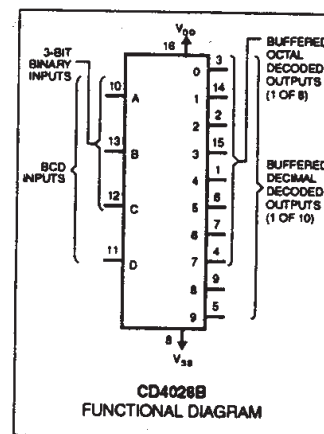
The CD4028B-Series types are supplied in 16-lead hermetic dual-in-line ceramic packages (D and F suffixes), 16-lead dual-in-line plastic packages (E suffix), and in chip form (H suffix).

Features:

- BCD-to-decimal decoding or binary-to-octal decoding
- High decoded output drive capability
- "Positive logic" inputs and outputs. decoded outputs go high on selection
- Medium-speed operation.
 $t_{PHL}, t_{PLH} = 80 \text{ ns (typ.) @ } V_{DD} = 10 \text{ V}$
- Standardized, symmetrical output characteristics
- 100% tested for quiescent current at 20 V
- Maximum input current of $1 \mu\text{A}$ at 18 V over full package-temperature range; 100 nA at 18 V and 25°C
- Noise margin (over full package-temperature range):
 1 V at $V_{DD} = 5 \text{ V}$
 2 V at $V_{DD} = 10 \text{ V}$
 2.5 V at $V_{DD} = 15 \text{ V}$
- 5-V, 10-V, and 15-V parametric ratings
- Meets all requirements of JEDEC Tentative Standard No. 13B, "Standard Specifications for Description of 'B' Series CMOS Devices"

Applications:

- Code conversion ■ Indicator-tube decoder
- Address decoding—memory selection control



Top View
TERMINAL DIAGRAM

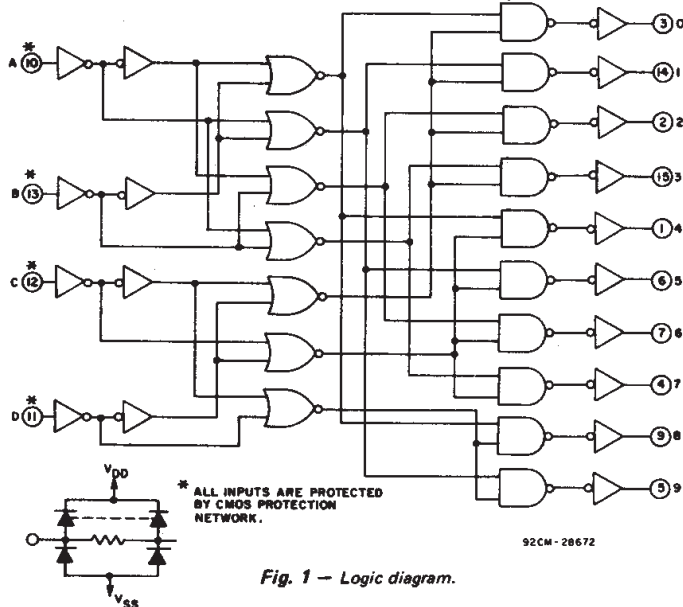


Fig. 1 — Logic diagram.

MAXIMUM RATINGS, Absolute-Maximum Values:

DC SUPPLY-VOLTAGE RANGE, (V_{DD})

Voltages referenced to V_{SS} Terminal) -0.5V to +20V

INPUT VOLTAGE RANGE, ALL INPUTS -0.5V to $V_{DD} + 0.5\text{V}$

DC INPUT CURRENT, ANY ONE INPUT $\pm 10\text{mA}$

POWER DISSIPATION PER PACKAGE (P_D):

For $T_A = -55^\circ\text{C}$ to $+100^\circ\text{C}$ 500mW

For $T_A = +100^\circ\text{C}$ to $+125^\circ\text{C}$ Derate Linearity at 12mW/ $^\circ\text{C}$ to 200mW

DEVICE DISSIPATION PER OUTPUT TRANSISTOR

For $T_A = \text{FULL PACKAGE-TEMPERATURE RANGE (All Package Types)}$ 100mW

OPERATING-TEMPERATURE RANGE (T_A) -55°C to $+125^\circ\text{C}$

STORAGE TEMPERATURE RANGE (T_{stg}) -65°C to $+150^\circ\text{C}$

LEAD TEMPERATURE (DURING SOLDERING):

At distance $1/16 \pm 1/32$ inch ($1.59 \pm 0.79\text{mm}$) from case for 10s max $+265^\circ\text{C}$

TABLE I — TRUTH TABLE

D	C	B	A	0	1	2	3	4	5	6	7	8	9
0	0	0	0	1	0	0	0	0	0	0	0	0	0
0	0	0	1	0	1	0	0	0	0	0	0	0	0
0	0	1	0	0	0	1	0	0	0	0	0	0	0
0	0	1	1	0	0	0	1	0	0	0	0	0	0
0	1	0	0	0	0	0	0	1	0	0	0	0	0
0	1	0	1	0	0	0	0	0	1	0	0	0	0
0	1	1	0	0	0	0	0	0	0	1	0	0	0
0	1	1	1	0	0	0	0	0	0	0	1	0	0
1	0	0	0	0	0	0	0	0	0	0	0	1	0
1	0	0	1	0	0	0	0	0	0	0	0	0	1
1	0	1	0	0	0	0	0	0	0	0	0	0	0
1	0	1	1	0	0	0	0	0	0	0	0	0	0
1	1	0	0	0	0	0	0	0	0	0	0	0	0
1	1	0	1	0	0	0	0	0	0	0	0	0	0
1	1	1	0	0	0	0	0	0	0	0	0	0	0
1	1	1	1	0	0	0	0	0	0	0	0	0	0

I = HIGH LEVEL

O = LOW LEVEL

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RECOMMENDED OPERATING CONDITIONS

For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges:

CHARACTERISTIC	LIMITS		UNITS
	MIN.	MAX.	
Supply Voltage Range (For T_A = Full Package Temperature Range)	3	18	V

STATIC ELECTRICAL CHARACTERISTICS

CHARACTER- ISTIC	CONDITIONS			LIMITS AT INDICATED TEMPERATURES (°C)							UNITS
	V _O (V)	V _{IN} (V)	V _{DD} (V)	+25							
				-55	-40	+85	+125	Min.	Typ.	Max.	
Quiescent Device Current, I _{DD} Max.	—	0,5	5	5	5	150	150	—	0.04	5	μA
	—	0,10	10	10	10	300	300	—	0.04	10	
	—	0,15	15	20	20	600	600	—	0.04	20	
	—	0,20	20	100	100	3000	3000	—	0.08	100	
Output Low (Sink) Current I _{OL} Min.	0.4	0,5	5	0.64	0.61	0.42	0.36	0.51	1	—	mA
	0.5	0,10	10	1.6	1.5	1.1	0.9	1.3	2.6	—	
	1.5	0,15	15	4.2	4	2.8	2.4	3.4	6.8	—	
Output High (Source) Current, I _{OH} Min.	4.6	0,5	5	-0.64	-0.61	-0.42	-0.36	-0.51	1	—	mA
	2.5	0,5	5	-2	-1.8	-1.3	-1.15	-1.6	-3.2	—	
	9.5	0,10	10	-1.6	-1.5	-1.1	-0.9	-1.3	-2.6	—	
	13.5	0,15	15	-4.2	-4	-2.8	-2.4	-3.4	-6.8	—	
Output Voltage: Low-Level, V _{OL} Max.	—	0,5	5	0.05				—	0	0.05	V
	—	0,10	10	0.05				—	0	0.05	
	—	0,15	15	0.05				—	0	0.05	
Output Voltage: High-Level, V _{OH} Min.	—	0,5	5	4.95				4.95	5	—	V
	—	0,10	10	9.95				9.95	10	—	
	—	0,15	15	14.95				14.95	15	—	
Input Low Voltage, V _{IL} Max.	0.5, 4.5	—	5	1.5				—	—	1.5	V
	1.9	—	10	3				—	—	3	
	1.5, 13.5	—	15	4				—	—	4	
Input High Voltage, V _{IH} Min.	0.5, 4.5	—	5	3.5				3.5	—	—	V
	1.9	—	10	7				7	—	—	
	1.5, 13.5	—	15	11				11	—	—	
Input Current I _{IN} Max.	—	0,18	18	±0,1	±0,1	±1	±1	—	±10 ⁻⁵	±0,1	μA

DYNAMIC ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ C$, $C_L = 50$ pF,

Input $t_r, t_f = 20$ ns, $R_L = 200$ k Ω

CHARACTERISTIC	TEST CONDITIONS	LIMITS		UNITS
	V_{DD} (V)	Typ.	Max.	
Propagation Delay Time: t_{PHL}, t_{PLH}	5	175	350	ns
	10	80	160	
	15	60	120	
Transition Time t_{THL}, t_{TLH}	5	100	200	ns
	10	50	100	
	15	40	80	
Input Capacitance, C_{IN}	—	5	7.5	pF

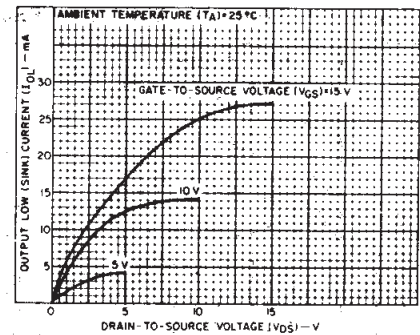


Fig. 2 — Typical output low (sink) current characteristics.

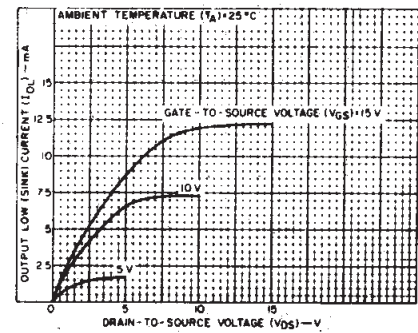


Fig. 3 — Minimum output low (sink) current characteristics.

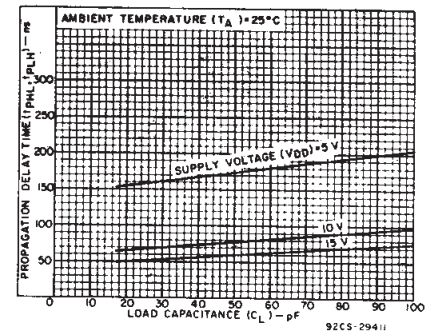


Fig. 4 — Typical propagation delay time as a function of load capacitance.

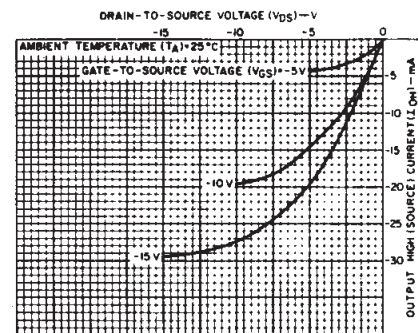


Fig. 5 — Typical output high (source) current characteristics.

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TABLE II — CODE CONVERSION CHART

INPUTS				INPUT CODES						OUTPUT NUMBER																
				Hexa - Decimal		Decimal																				
						4BIT BINARY	4BIT GRAY	EXCESS-3	EXCESS-3 GRAY																	AIKEN
D	C	B	A								0	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15
0	0	0	0	0	0				0	0	1	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0
0	0	0	1	1	1				1	1	0	1	0	0	0	0	0	0	0	0	0	0	0	0	0	0
0	0	1	0	2	3		0	2	2		0	0	1	0	0	0	0	0	0	0	0	0	0	0	0	0
0	0	1	1	3	2	0	3	3			0	0	0	1	0	0	0	0	0	0	0	0	0	0	0	0
0	1	0	0	4	7	1	4	4			0	0	0	0	1	0	0	0	0	0	0	0	0	0	0	0
0	1	0	1	5	6	2			3		0	0	0	0	0	1	0	0	0	0	0	0	0	0	0	0
0	1	1	0	6	4	3	1		4		0	0	0	0	0	0	1	0	0	0	0	0	0	0	0	0
0	1	1	1	7	5	4	2				0	0	0	0	0	0	0	1	0	0	0	0	0	0	0	0
1	0	0	0	8	15	5					0	0	0	0	0	0	0	0	1	0	0	0	0	0	0	0
1	0	0	1	9	14	6			5		0	0	0	0	0	0	0	0	0	1	0	0	0	0	0	0
1	0	1	0	10	12	7	9		6		0	0	0	0	0	0	0	0	0	0	1	0	0	0	0	0
1	0	1	1	11	13	8		5			0	0	0	0	0	0	0	0	0	0	0	1	0	0	0	0
1	1	0	0	12	8	9	5	6			0	0	0	0	0	0	0	0	0	0	0	0	1	0	0	0
1	1	0	1	13	9		6	7	7		0	0	0	0	0	0	0	0	0	0	0	0	0	1	0	0
1	1	1	0	14	11		8	8	8		0	0	0	0	0	0	0	0	0	0	0	0	0	0	1	0
1	1	1	1	15	10		7	9	9		0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	1

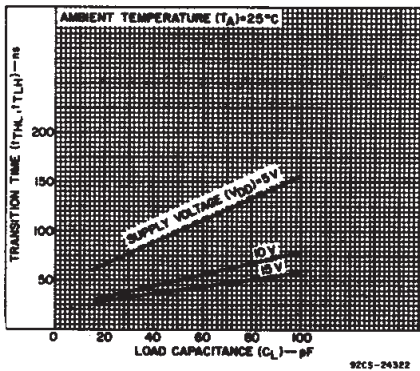


Fig. 8 — Typical transition time as a function of load capacitance.

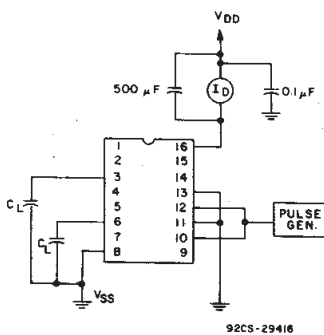


Fig. 10 — Dynamic power dissipation test circuit.

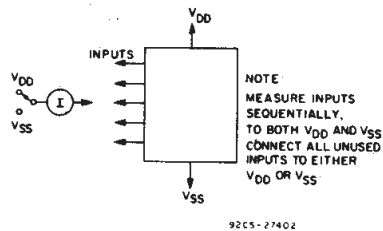


Fig. 9 — Input current test circuit.

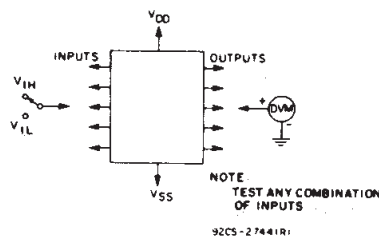


Fig. 11 — Input voltage test circuit.

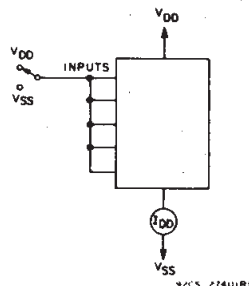


Fig. 12 — Quiescent device current test circuit.

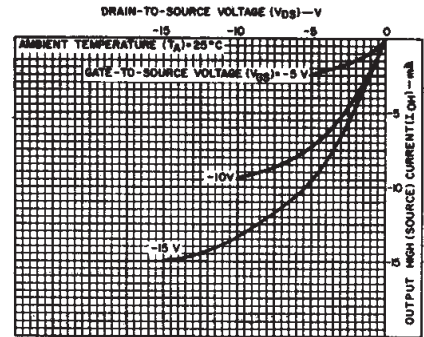


Fig. 6 — Minimum output high (source) current characteristics.

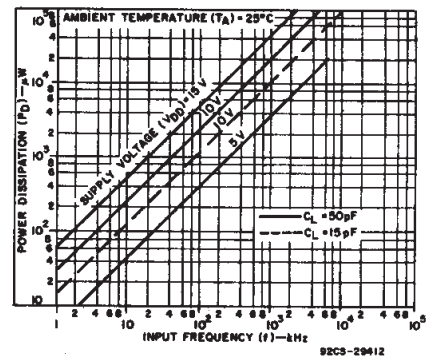


Fig. 7 — Typical dynamic power dissipation as a function of input frequency.

TYPICAL APPLICATIONS

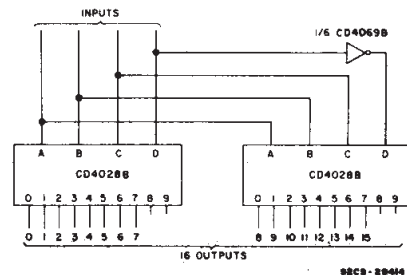
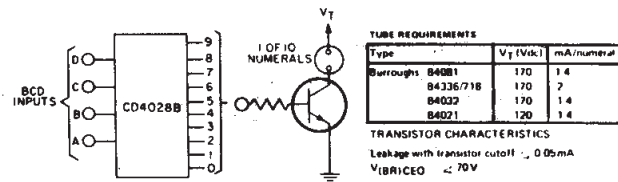


Fig. 13 — Code conversion circuit.

The circuit shown in Fig.13 converts any 4-bit code to a decimal or hexadecimal code. Table 2 shows a number of codes and the decimal or hexadecimal number in these codes which must be applied to the input terminals of the CD4028B to select a particular output. For example: in order to get a high on output No. 8 the input must be either an 8 expressed in 4-Bit Binary code, a 15 expressed in 4-Bit Gray code, or a 5 expressed in Excess-3 code.

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92CS-29413

Fig. 14 — Neon readout (Nixie Tube[^]) display application.

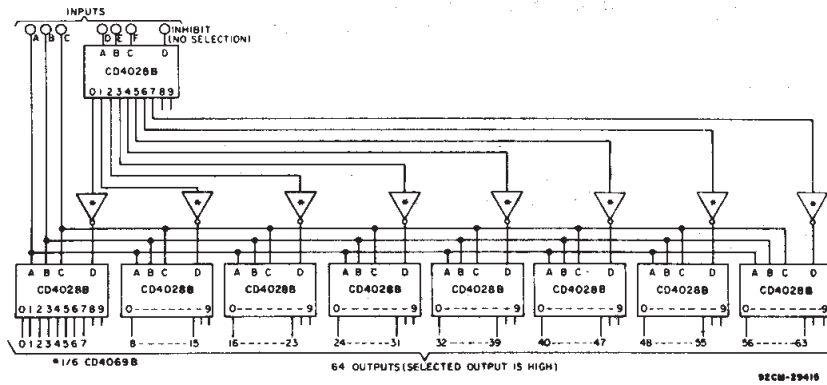
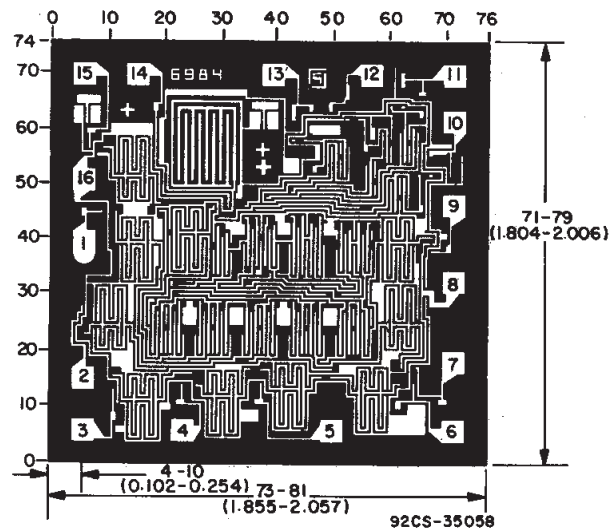


Fig. 15 — 6-bit binary to 1-of-64 address decoder.



CD4028BH DIMENSIONS AND PAD LAYOUT

Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils (10^{-3} inch).

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